



3.3V CMOS 16-BIT LATCHED TRANSCEIVER

IDT74FCT163543/A/C

FEATURES:

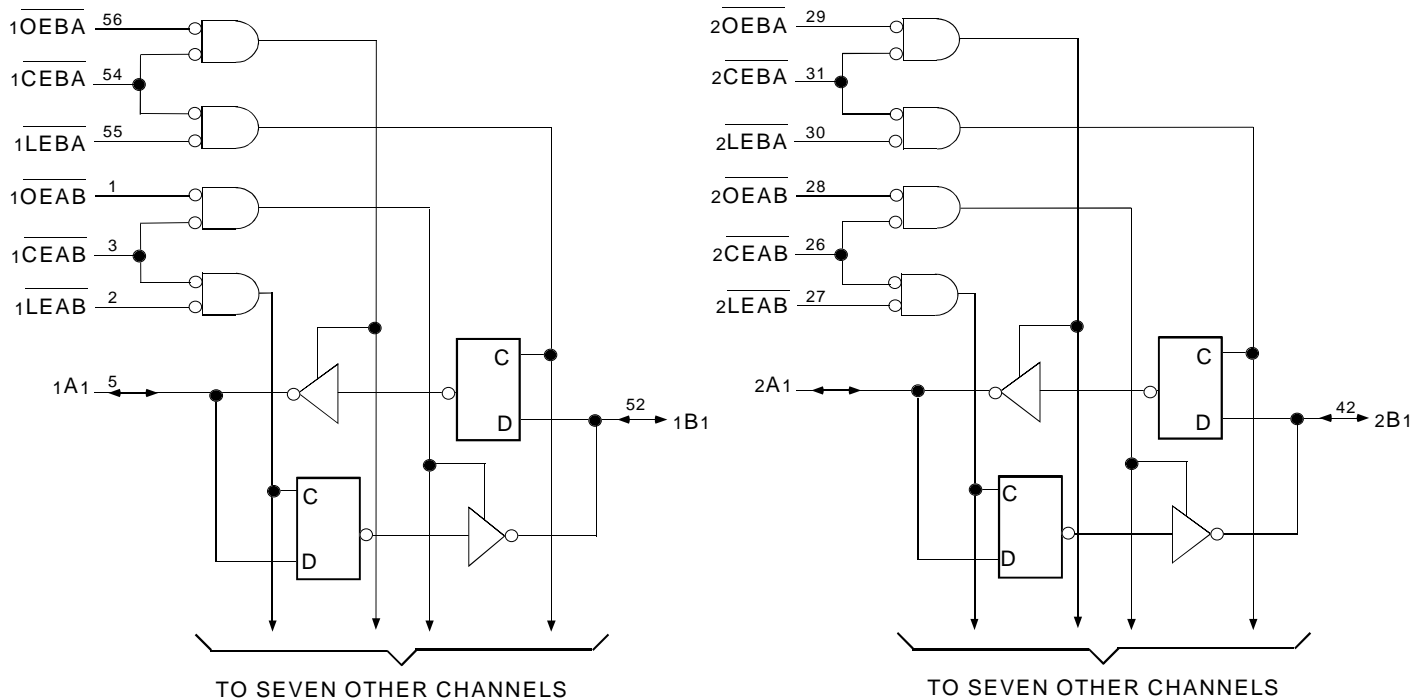
- 0.5 MICRON CMOS Technology
- Typical $t_{sk(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- 25 mil pitch SSOP, 19.6 mil pitch TSSOP and 15.7 mil pitch TVSOP Packages
- Extended commercial range of -40°C to +85°C
- $V_{cc} = 3.3V \pm 0.3V$, Normal Range or $V_{cc} = 2.7V$ to 3.6V, Extended Range
- CMOS power levels (0.4μW typ. static)
- Rail-to-Rail output swing for increased noise margin
- Low Ground Bounce (0.3V typ.)
- Inputs (except I/O) can be driven by 3.3V or 5V components

DESCRIPTION:

The FCT163543/A/C 16-bit latched transceivers are built using advanced dual metal CMOS technology. These high-speed, low-power devices are organized as two independent 8-bit D-type latched transceivers with separate input and output control to permit independent control of data flow in either direction. For example, the A-to-B Enable (\overline{xCEAB}) must be low in order to enter data from the A port or to output data from the B port. \overline{xLEAB} controls the latch function. When \overline{xLEAB} is low, the latches are transparent. A subsequent low-to-high transition of \overline{xLEAB} signal puts the A latches in the storage mode. \overline{xOEAB} performs output enable function on the B port. Data flow from the B port to the A port is similar but requires using \overline{xCEBA} , \overline{xLEBA} , and \overline{xOEBA} inputs. Flow-through organization of signal pins simplifies layout. All inputs are designed with hysteresis for improved noise margin.

The FCT163543/A/C have series current limiting resistors. These offer low ground bounce, minimal undershoot, and controlled output fall times—reducing the need for external series terminating resistors.

FUNCTIONAL BLOCK DIAGRAM



-
-
-
-
-
-
-
-
-
-
-
-
-
-
-
-

-
-
-
-

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Commercial: TA = -40°C to +85°C, VCC = 2.7V to 3.6V

Symbol	Parameter	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
--------	-----------	--------------------------------	------	---------------------	------	------

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit	
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$ $V_{IN} = V_{CC} - 0.6V^{(3)}$	—	2	30	μA	
I_{CCD}	Dynamic Power Supply Current ⁽⁴⁾	$V_{CC} = \text{Max.}$, Outputs Open xCEAB and xOEAB = GND xCEBA = V_{CC} One Input Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = GND$	—	60	100	$\mu A / \text{MHz}$
I_C	Total Power Supply Current ⁽⁶⁾	$V_{CC} = \text{Max.}$, Outputs Open $f_i = 10\text{MHz}$ 50% Duty Cycle xLEAB, xCEAB and xOEAB = GND xCEBA = V_{CC} One Bit Toggling	$V_{IN} = V_{CC}$ $V_{IN} = GND$	—	0.6	1	mA
			$V_{IN} = V_{CC} - 0.6V$ $V_{IN} = GND$	—	0.6	1	
		$V_{CC} = \text{Max.}$, Outputs Open $f_i = 2.5\text{MHz}$ 50% Duty Cycle xLEAB, xCEAB and xOEAB = GND xCEBA = V_{CC} Sixteen Bits Toggling	$V_{IN} = V_{CC}$ $V_{IN} = GND$	—	2.4	4 ⁽⁵⁾	
			$V_{IN} = V_{CC} - 0.6V$ $V_{IN} = GND$	—	2.4	4.3 ⁽⁵⁾	

NOTES:

- For conditions shown as max. or min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at $V_{CC} = 3.3V$, $+25^\circ C$ ambient.
- Per TTL driven input; all other inputs at V_{CC} or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
- $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP} N_{CP} / 2 + f_i N_i)$
 $I_{CC} = \text{Quiescent Current (} I_{CCL}, I_{CCH} \text{ and } I_{CCZ})$
 $\Delta I_{CC} = \text{Power Supply Current for a TTL High Input}$
 $D_H = \text{Duty Cycle for TTL Inputs High}$
 $N_T = \text{Number of TTL Inputs at } D_H$
 $I_{CCD} = \text{Dynamic Current Caused by an Input Transition Pair (HLH or LHL)}$
 $f_{CP} = \text{Clock Frequency for Register Devices (Zero for Non-Register Devices)}$
 $N_{CP} = \text{Number of Clock Inputs at } f_{CP}$
 $f_i = \text{Input Frequency}$
 $N_i = \text{Number of Inputs at } f_i$

SWITCHING CHARACTERISTICS OVER OPERATING RANGE (4)

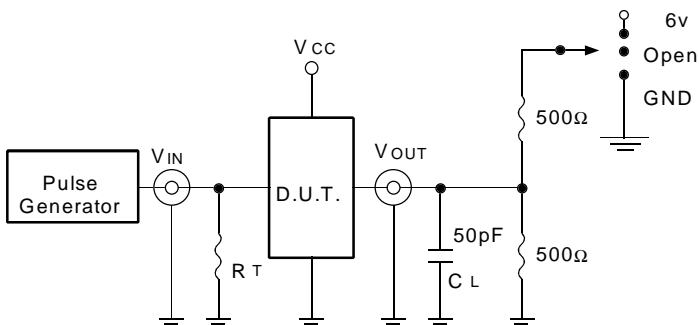
Symbol	Parameter	Condition ⁽¹⁾	FCT163543		FCT163543A		FCT163543C		Unit
			Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	
t _{PLH} t _{PHL}	Propagation Delay Transparent Mode xAx to xBx or xBx to xAx	CL = 50pF RL = 500Ω	1.5	8.5	1.5	6.5	1.5	5.3	ns
t _{PLH} t _{PHL}	Propagation Delay xLEB \bar{A} to xAx, xLEAB to xBx		1.5	12.5	1.5	8	1.5	7	ns
t _{PZH} t _{PZL}	Output Enable Time xOEBA or xOEAB to xAx or xBx xCEBA or xCEAB to xAx or xBx		1.5	12	1.5	9	1.5	8	ns
t _{PHZ} t _{PLZ}	Output Disable Time xOEBA or xOEAB to xAx or xBx xCEBA or xCEAB to xAx or xBx		1.5	9	1.5	7.5	1.5	6.5	ns
t _{SU}	Set-up Time HIGH or LOW xAx or xBx to xLEAB or xLEBA		3	—	2	—	2	—	ns
t _H	Hold Time HIGH or LOW xAx or xBx to xLEAB or xLEBA		2	—	2	—	2	—	ns
t _w	xLEBA or xLEAB Pulse Width LOW		5	—	5	—	5	—	ns
t _{SK(0)}	Output Skew ⁽³⁾		—	0.5	—	0.5	—	0.5	ns

NOTES:

1. See test circuits and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.
4. Propagation Delays and Enable/Disable times are with V_{CC} = 3.3V ±0.3V, Normal Range. For V_{CC} = 2.7V to 3.6V, Extended Range, all Propagation Delays and Enable/Disable times should be degraded by 20%.

TEST CIRCUITS AND WAVEFORMS

TEST CIRCUITS FOR ALL OUTPUTS



SWITCH POSITION

Test	Switch
Open Drain	6V
Disable Low	
Enable Low	
Disable High	GND
Enable High	
All Other Tests	Open

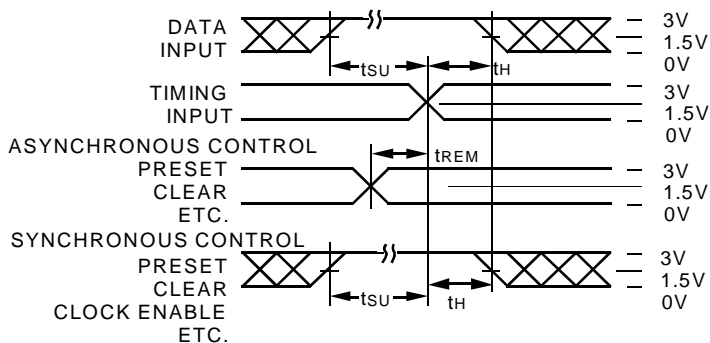
3v16-link

DEFINITIONS:

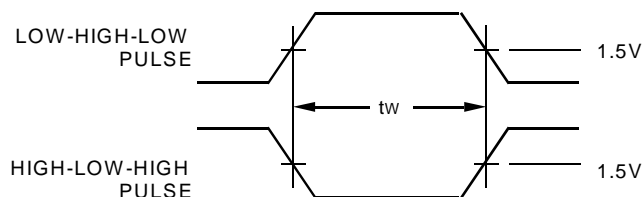
CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

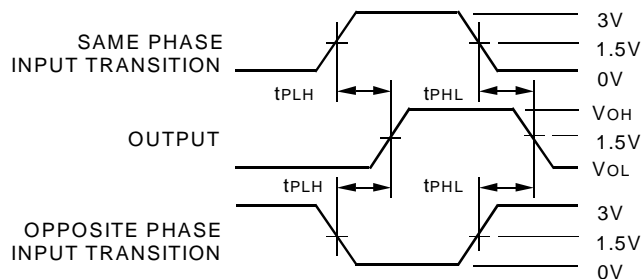
SET-UP, HOLD, AND RELEASE TIMES



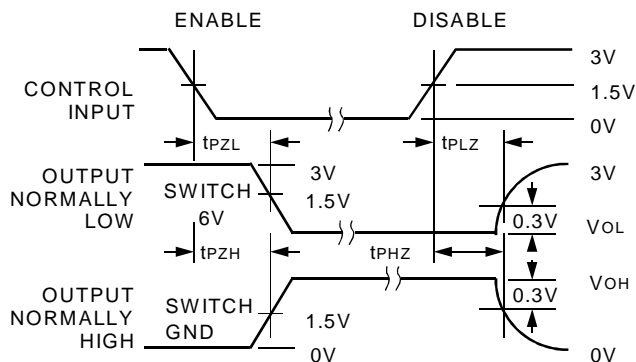
PULSE WIDTH



PROPAGATION DELAY



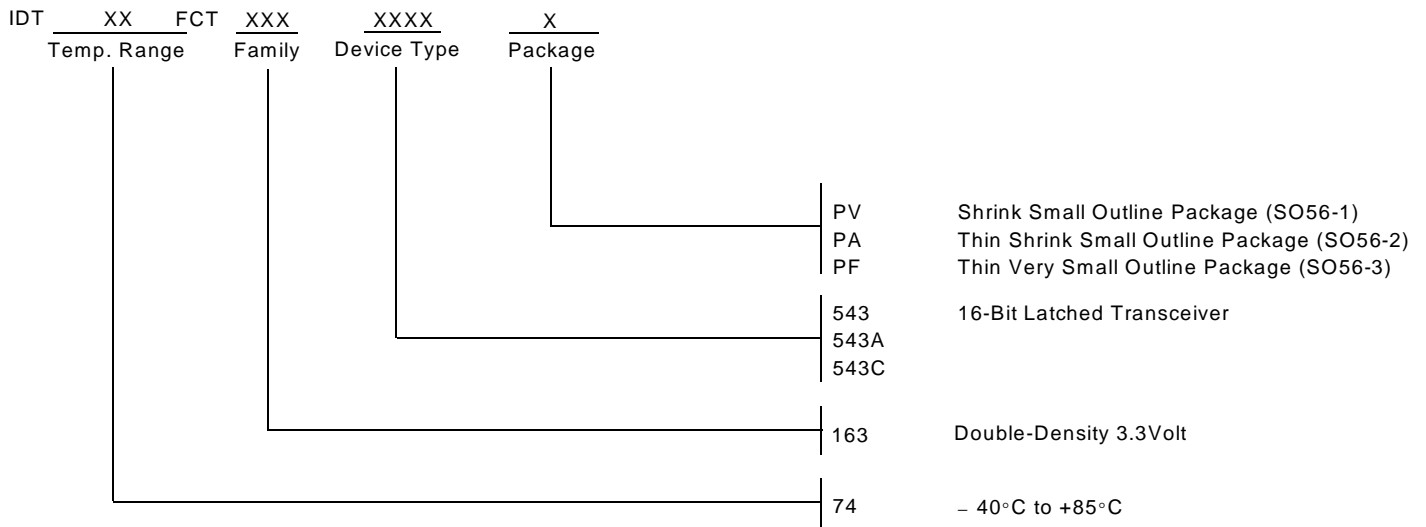
ENABLE AND DISABLE TIMES



NOTES:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
2. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $t_f \leq 2.5\text{ns}$; $t_r \leq 2.5\text{ns}$.
3. If V_{CC} is below 3V, input voltage swings should be adjusted not to exceed V_{CC} .

ORDERING INFORMATION



CORPORATE HEADQUARTERS
 2975 Stender Way
 Santa Clara, CA 95054

for SALES:
 800-345-7015 or 408-727-6116
 fax: 408-492-8674
www.idt.com*

**To search for sales office near you, please click the sales button found on our home page or dial the 800# above and press 2.
 The IDT logo is a registered trademark of Integrated Device Technology, Inc.*